Silicon Epitaxial Planar Diode for High Speed Switching

# **HITACHI**

ADE-208-180A (Z) Rev. 1 Aug. 1995

## **Features**

- Low capacitance. (C = 3.0pF max)
- Short reverse recovery time.  $(t_{rr} = 3.5 \text{ns max})$
- Small glass package (MHD) enables easy mounting and high reliability.

  rdering Information

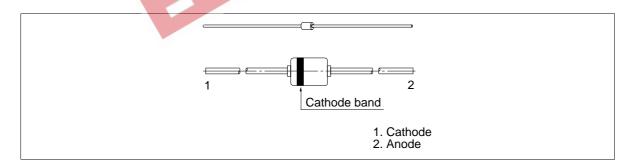
  pe No.

  Cathode band

## **Ordering Information**

| Type No. | Cathode band | Package Code |
|----------|--------------|--------------|
| 1SS119   | Light Blue   | MHD          |

## **Outline**





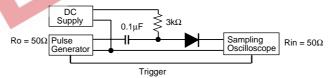
## **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

| Item                                      | Symbol             | Value       | Unit |
|---|--------------------|-------------|------|
| Peak reverse voltage                      | $V_{RM}$           | 35          | V    |
| Reverse voltage                           | $V_R$              | 30          | V    |
| Peak forward current                      | I <sub>FM</sub>    | 450         | mA   |
| Non-Repetitive peak forward surge current | I <sub>FSM</sub> * | 1           | A    |
| Average forward current                   | Io                 | 150         | mA   |
| Power dissipation                         | Pd                 | 250         | mW   |
| Junction temperature                      | Tj                 | 175         | °C   |
| Storage temperature                       | Tstg               | -65 to +175 | °C   |

## **Electrical Characteristics** (Ta = 25°C)

| Note: Within 1s forward surge current. |                   |     |           |     |      |   |  |  |  |
|--|-------------------|-----|-----------|-----|------|---|--|--|--|
| Electrical Characte                    | $a = 25^{\circ}$  | C)  | 3 The Con |     |      |   |  |  |  |
| Item                                   | Symbol            | Min | Тур       | Max | Unit | Test Condition  |  |  |  |
| Forward voltage                        | $V_{F}$           | -   |           | 0.8 | V    | I <sub>F</sub> = 10mA                                   |  |  |  |
| Reverse current                        | I <sub>R</sub>    |     | + /       | 0.1 | μА   | V <sub>R</sub> = 30V                                    |  |  |  |
| Capacitance                            | С                 |     | 7         | 3.0 | pF   | V <sub>R</sub> = 1V, f = 1MHz                           |  |  |  |
| Reverse recovery time                  | t <sub>rr</sub> * |     | _         | 3.5 | ns   | $I_F = 10 \text{mA}, V_R = 6 \text{V}, R_L = 50 \Omega$ |  |  |  |

Note: Reverse recovery time test circuit



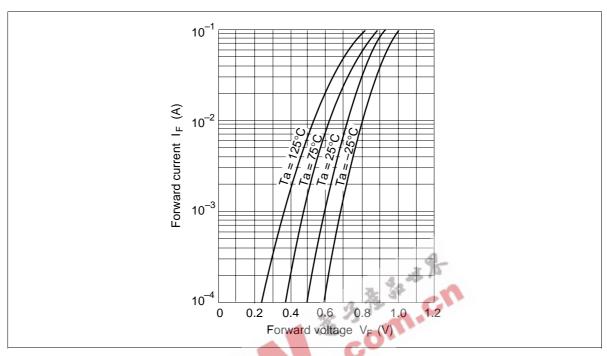


Fig.1 Forward current Vs. Forward voltage

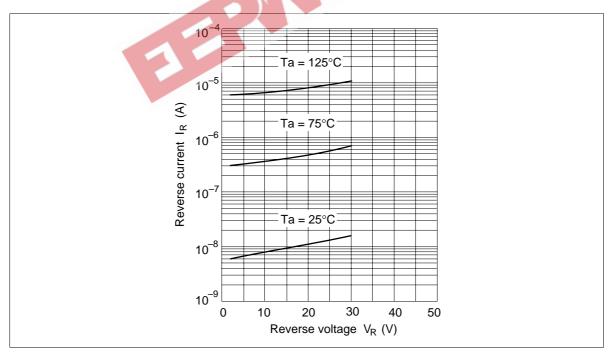


Fig.2 Reverse current Vs. Reverse voltage

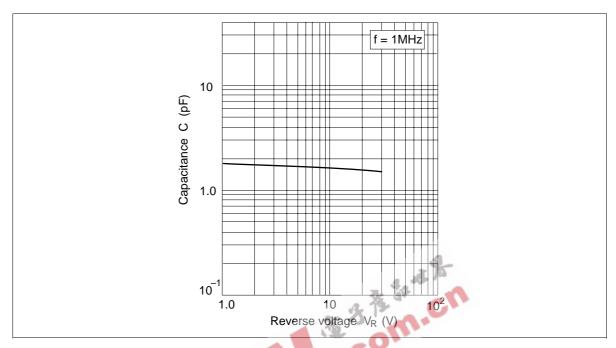
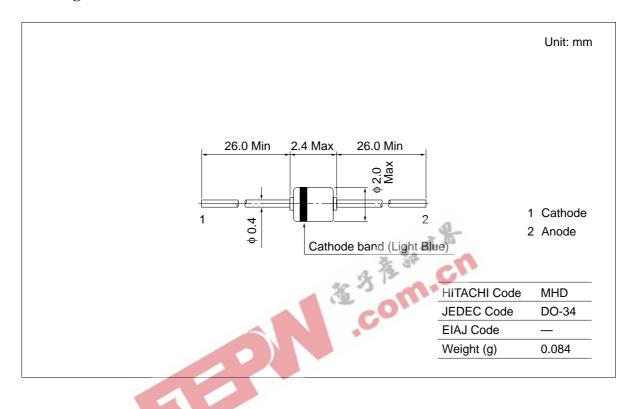


Fig.3 Capacitance Vs. Reverse voltage

## **Package Dimensions**



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